Power MOSFET

-30 V, -5.9 A, μCool[™] Single P-Channel, 2x2 mm, WDFN Package

Features

- WDFN Package with Exposed Drain Pad for Excellent Thermal Conduction
- 2x2 mm Footprint Same as SC-88 Package
- Low Profile (< 0.8 mm) for Easy Fit in Thin Environments
- This is a Pb-Free Device

Applications

- Li Ion Battery Linear Mode Charging for Portable Power Management in Noisy Environment
- DC-DC Conversion Buck/Boost Circuits
- High Side Switching

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Paran	Symbol	Value	Unit		
Drain-to-Source Voltag	V _{DSS}	-30	V		
Gate-to-Source Voltag	je		V _{GS}	±12	V
Continuous Drain	Steady	T _A = 25°C		-4.5	А
Current (Note 1)	State	T _A = 85°C	I _D	-3.3	
	t ≤ 5 s	$T_A = 25^{\circ}C$		-5.9	
Power Dissipation (Note 1)	Steady State	T _A = 25°C	PD	1.9	W
	t ≤ 5 s		2	3.2	
Continuous Drain		T _A = 25°C		-2.7	А
Current (Note 2)	Steady State	$T_A = 85^{\circ}C$	I _D	-2.0	
Power Dissipation (Note 2)		State	$T_A = 25^{\circ}C$	PD	0.7
Pulsed Drain Current	t _p =	10 μs	I _{DM}	-18	А
Operating Junction and	T _J , T _{STG}	-55 to 150	°C		
Source Current (Body	ا _S	-1.5	А		
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Surface Mounted on FR4 Board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
- 2. Surface Mounted on FR4 Board using the minimum recommended pad size.



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V _{(BR)DSS}	R _{DS(on)} MAX
-30 V	62 mΩ @ -4.5 V
-30 V	75 mΩ @ -2.5 V



P-CHANNEL MOSFET





(Top View)

ORDERING INFORMATION

Device	Package	Shipping [†]
NTLJS4149PTAG	WDFN6 (Pb-Free)	3000/Tape & Reel
NTLJS4149PTBG	WDFN6 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Мах	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{ hetaJA}$	65	°C/W
Junction-to-Ambient – t \leq 5 s (Note 3)	$R_{ hetaJA}$	38	
Junction-to-Ambient - Steady State Min Pad (Note 4)	R _{θJA}	180	

Surface Mounted on FR4 Board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
Surface Mounted on FR4 Board using the minimum recommended pad size.

MOSFET ELECTRICAL CHARACTERISTICS (T₁ = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions		Min	Тур	Мах	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = -25	50 μA	-30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = -250 μA, Ref to) 25°C		-1.8		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$\lambda = 24 \lambda \lambda = 0 \lambda$	T _J = 25°C		-0.1	-1.0	μA
		$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$	T _J = 85°C		-1.0	-10	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±	12 V			±0.1	μΑ
ON CHARACTERISTICS (Note 5)							-
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D} = -250 \ \mu A$		-0.4		-1.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				3.1		mV/°C
Drain-to-Source On-Resistance	R _{DS(on)}	V_{GS} = -4.5 V, I _D = -2.0 A			43	62	mΩ
		V_{GS} = -2.5 V, I _D = -	-2.0 A		56	75	
		V_{GS} = -4.5 V, I _D = -4.5 A			43	62	
Forward Transconductance	9 FS	$V_{DS} = -6.0 \text{ V}, \text{ I}_{D} = -3.0 \text{ A}$			10		S
CHARGES, CAPACITANCES AND GA	ATE RESISTAN	CE					
Input Capacitance	C _{ISS}				960		pF
Output Capacitance	C _{OSS}	V _{GS} = 0 V, f = 1.0 M V _{DS} = -15 V	ИНZ,		130		
Reverse Transfer Capacitance	C _{RSS}	VDS - 10 V			80		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = -4.5 V, V _{DS} = -15 V, I _D = -2.0 A			9.9	15	nC
Threshold Gate Charge	Q _{G(TH)}				0.8		
Gate-to-Source Charge	Q _{GS}				1.45		
Gate-to-Drain Charge	Q _{GD}				2.75		

SWITCHING CHARACTERISTICS (Note 6)

Turn-On Delay Time	t _{d(ON)}		6.9	ns
Rise Time	t _r	V _{GS} = -4.5 V, V _{DS} = -15 V,	11	
Turn-Off Delay Time	t _{d(OFF)}	I_D = -2.0 A, R_G = 2.0 Ω	60	
Fall Time	t _f		55	

DRAIN-SOURCE DIODE CHARACTERISTICS

Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = -1.5 A	T _J = 25°C	-0.75	-1.2	V
		VGS - 0 V, IS1.3 A	T _J = 85°C	-0.65		v
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V}, \text{ d}_{IS}/\text{d}_{t} = 100 \text{ A}/\mu\text{s},$ $I_{S} = -1.5 \text{ A}$		35	60	
Charge Time	t _a			10		ns
Discharge Time	t _b	I _S = -1.5 A		25		
Reverse Recovery Charge	Q _{RR}	1		0.016		μC

5. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%. 6. Switching characteristics are independent of operating junction temperatures.



TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)



TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)











Figure 10. Diode Forward Voltage versus Current





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DESCRIPTION:	6 PIN WDFN 2X2, 0.65P		PAGE 1 OF 1	

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